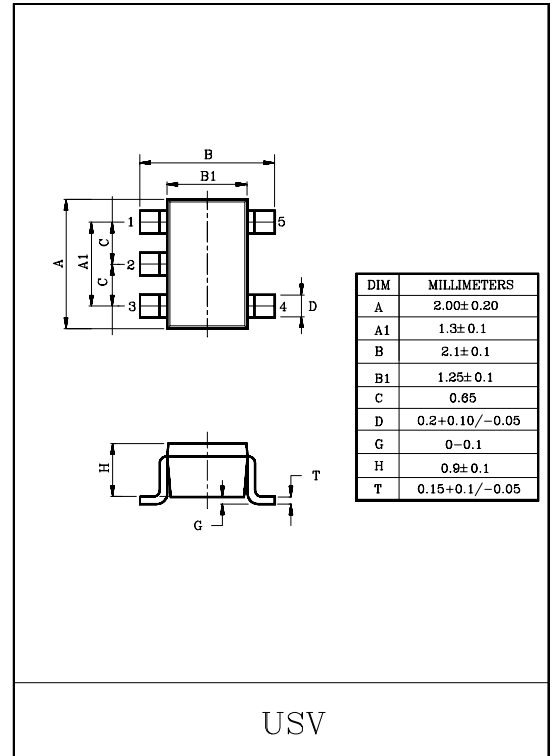


## EXCLUSIVE OR GATE

The KIC7S86FU is a high speed C<sup>2</sup>MOS EXCLUSIVE OR GATE fabricated with silicon gate C<sup>2</sup>MOS technology. It achieves high speed operation similar to equivalent LSTTL while maintaining the C<sup>2</sup>MOS low power dissipation. Input and output buffers are provided which offer high noise immunity and stable output. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

## FEATURES

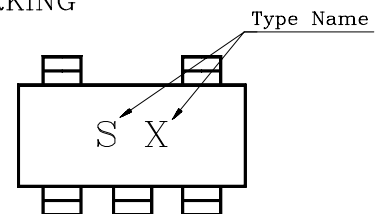
- High Speed :  $t_{pd}=10\text{ns(Typ.)}$  at  $V_{CC}=5\text{V}$ .
- Low Power Dissipation :  $I_{CC}=1\mu\text{A(Max.)}$  at  $T_a=25^\circ\text{C}$ .
- High Noise Immunity :  $V_{NIH}=V_{NIL}=28\% V_{CC(\text{Min.})}$ .
- Output Drive Capability : 5 LSTTL Loads.
- Symmetrical Output Impedance :  $|I_{OH}|=I_{OL}=2\text{mA(Min.)}$
- Balanced Propagation Delays :  $t_{pLH}\approx t_{pHL}$
- Wide Operating Voltage Range :  $V_{CC(\text{opr})}=2\sim 6\text{V}$ .



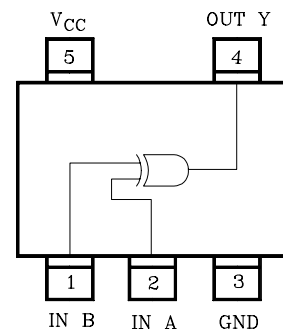
## MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7	V
DC Input Voltage	$V_{IN}$	-0.5~ $V_{CC}+0.5$	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC}+0.5$	V
Input Diode Current	$I_{IK}$	±20	mA
Output Diode Current	$I_{OK}$	±20	mA
DC Output Current	$I_{OUT}$	±12.5	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	±25	mA
Power Dissipation	$P_D$	200	mW
Storage Temperature	$T_{stg}$	-65~150	°C
Lead Temperature (10s)	$T_L$	260	°C

## MARKING

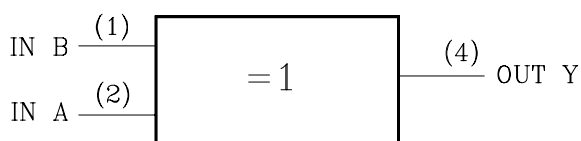


## PIN CONNECTION(TOP VIEW)



# KIC7S86FU

## LOGIC DIAGRAM



## TRUTH TABLE

A	B	Y
H	H	L
L	H	H
H	L	H
L	L	L

## RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	$V_{CC}$	2~6	V
Input Voltage	$V_{IN}$	0~ $V_{CC}$	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	$t_r, t_f$	0~1000 ( $V_{CC}=2.0V$ ) 0~ 500 ( $V_{CC}=4.5V$ ) 0~ 400 ( $V_{CC}=6.0V$ )	ns

## DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION	$T_a=25^\circ C$			$T_a=-40\sim 85^\circ C$		UNIT		
			$V_{CC}$	MIN.	TYP.	MAX.	MIN.		MAX.	
High-Level Input Voltage	$V_{IH}$	-	2.0	1.5	-	-	1.5	-	V	
			4.5	3.15	-	-	3.15	-		
			6.0	4.2	-	-	4.2	-		
Low-Level Input Voltage	$V_{IL}$	-	2.0	-	-	0.5	-	0.5	V	
			4.5	-	-	1.35	-	1.35		
			6.0	-	-	1.8	-	1.8		
High-Level Output Voltage	$V_{OH}$	$V_{IN}=V_{IH}$ or $V_{IL}$	$I_{OH}=-20\mu A$	2.0	1.9	2.0	-	1.9	-	V
			$I_{OH}=-2mA$	4.5	4.4	4.5	-	4.4	-	
			$I_{OH}=-2.6mA$	6.0	5.9	6.0	-	5.9	-	
Low-Level Output Voltage	$V_{OL}$	$V_{IN}=V_{IL}$ or $V_{IH}$	$I_{OL}=20\mu A$	2.0	-	0.0	0.1	-	0.1	V
			$I_{OL}=2mA$	4.5	-	0.0	0.1	-	0.1	
			$I_{OL}=2.6mA$	6.0	-	0.0	0.1	-	0.1	
Input Leakage Current	$I_{IN}$	$V_{IN}=V_{CC}$ or GND	6.0	-	-	$\pm 0.1$	-	$\pm 1.0$	$\mu A$	
Quiescent Supply Current	$I_{CC}$	$V_{IN}=V_{CC}$ or GND	6.0	-	-	1.0	-	10.0		

# KIC7S86FU

AC ELECTRICAL CHARACTERISTICS ( $C_L=15\text{pF}$ ,  $V_{CC}=5\text{V}$ ,  $T_a=25^\circ\text{C}$ , Input  $t_r=t_f=6\text{ns}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta=25°C			UNIT
			MIN.	TYP.	MAX.	
Output Transition Time	$t_{TLH}$ $t_{THL}$	-	-	4	8	ns
Propagation Delay Time	$t_{pLH}$ $t_{pHL}$	-	-	10	17	

AC ELECTRICAL CHARACTERISTICS ( $C_L=50\text{pF}$ , Input  $t_r=t_f=6\text{ns}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	$V_{CC}$	Ta=25°C			Ta=-40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	$t_{TLH}$ $t_{THL}$	-	2.0	-	50	125	-	155	ns
			4.5	-	14	25	-	31	
			6.0	-	12	21	-	26	
Propagation Delay Time	$t_{pLH}$ $t_{pHL}$	-	2.0	-	48	100	-	125	
			4.5	-	12	20	-	25	
			6.0	-	9	17	-	21	
Input Capacitance	$C_{IN}$	-	-	5	10	-	10	pF	
Power Dissipation Capacitance	$C_{PD}$	(Note 1)	-	18	-	-	-		

Note 1 :  $C_{PD}$  defined as the value of internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$